NSN 5961-01-100-8579

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-100-8579 **Inclosure Material:** Plastic **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.6 on-state voltage, average **Current Rating Per Characteristic:** 3.00 amperes forward current, total rms universal **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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